## ABSTRACT OF THE DISCLOSURE

A semiconductor wafer made from silicon which is doped with hydrogen. The hydrogen concentration is less than 5\*10<sup>16</sup> atcm<sup>-3</sup> and greater than 1\*10<sup>12</sup> atcm<sup>-3</sup>. A method for producing a semiconductor wafer from silicon includes separating the semiconductor wafer from a silicon single crystal, with the single silicon crystal being pulled from a melt, in the presence of hydrogen, using the Czochralski method. The hydrogen partial pressure during the pulling of the single silicon crystal is less than 3 mbar.